

### **High Power PIN Diodes**

V16

#### **Features**

- High Power Handling
- Low Loss / Low Distortion
- Voltage Ratings up to 1000 Volts
- · Passivated Chip for Low Leakage Current
- Low Theta (θ) Due to Full Face Chip Bonding
- Leadless Low Inductance MELF Packages
- Various Package Options
- Available as Chips
- · Fully RoHS Compliant
- Non-Magnetic Packages Available for MRI

### **Description**

The MELF and HIPAX PIN diode series are designed for usage in switch and attenuator applications requiring high power handling and low distortion. These diodes incorporate a fully passivated PIN diode chip resulting in an extremely leakage current. reverse bias semiconductor technology utilized in the MELF and HIPAX families draws on MACOM 's substantial experience in PIN diode design and wafer fabrication. The result is a device which has a thick I-region and long carrier lifetime while maintaining low series resistance and capacitance values. The chips of the MELF and HIPAX PIN diodes are enclosed in a rugged ceramic package and is full face bonded to metal pins on both the anode and cathode. The result is a low loss PIN diode with low thermal resistance due to symmetrical thermal paths. The parts are offered in either magnetic or non-magnetic, HIPAX (axial leaded) or MELF (Metal Electrode Leadless Faced) surface mount packages for MRI applications. The MELF is a rectangular SMQ, package which is designed for high volume tape and reel assembly. This easy to use package design makes automatic pick and place, indexing and assembly, extremely easy. The parallel flat surfaces are suitable for most key jaw or vacuum pickup techniques. All of the solderable surfaces are tin plated and compatible with industry standard reflow and vapor phase soldering processes. See Application Note M538 for a typical solder reflow profile.

Many of MACOM's HIPAX PIN diodes are also available as chips. Please consult the "Silicon PIN Chip Datasheet" for availability and specifications.

### **Package Styles**



1072 & 1091

### **Applications**

HIPAX PIN diodes are designed for use in a wide variety of switch and attenuator applications from HF through UHF frequencies and at power levels above 1 kW, CW. The internal chip as well as each diode assembly has been comprehensively tested and characterized to ensure predictable and repeatable performance.

### **Design Recommendations**

- Low Distortion Attenuators MA4P4301B
- Surface Mount Switches MA4P7101F
- Cellular Radio Antenna Switches MA4P1200, MA4P1250

# Absolute Maximum Ratings $T_{\Delta} = +25^{\circ}\text{C} \text{ (Unless Otherwise Noted)}^{1}$

Parameter	Absolute Maximum
DC Reverse Voltage (V <sub>R</sub> )	(See Tables)
Operating Chip Junction Temperature	-55°C to +175°C
Storage Temperature	-55°C to +200°C
Installation Temperature	+280°C for 30 Seconds
ESD	Class 1A, HBM

#### Notes

1. Operation of this device above any one of these parameters may cause permanent damage.



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## MA4P1000 Series Electrical Specifications @ T<sub>A</sub> = +25°C

Part # (NM Indicates Non- Magnetic)	Total Cap	$ \begin{array}{c cccc} C_T & V_R & R_S \\ Capacitance & Reverse Voltage \\ pF & VDC & Series Resistance \\ W & & & & & & & \\ \hline 50 \ V, 1 \ MHz & I_R = 10 \ mA & I_F = 50 \ mA, 100 \ MHz \\ \end{array} $		R <sub>P</sub> Parallel Resistance kW  V <sub>R</sub> = 0 V, 100 MHz			
	Тур.	Max.	Min.	Max.	Тур.	Max.	Min.
MA4P1200 - 401T	1.2	1.5					
MA4P1200NM - 401T	1.2	1.5					
MA4P1250 -1072T	8.0	1.2	50	100	0.5	0.75	5
MA4P1250NM -1072T	0.8	1.2					
MA4P1450 -1091T	1.8	2.5					

Part #	Forward	V <sub>F</sub> Forward Voltage Max. I <sub>Forward</sub> @ 1V ≤		T <sub>∟</sub> Carrier Lifetime		Forward Bias Harmonic Distortion R(2a/a) * R(3a/a)		Reverse Bias Harmonic Distortion R(2a/a) – R(3a/a)				
(NM Indicates Non- Magnetic)	I <sub>F</sub> = 5	0 mA	14   1-= 10 m4  -= 6 m4   "		I <sub>F</sub> = 10 mA, I <sub>R</sub> = 6 mA		I <sub>F</sub> = 10 mA, I <sub>R</sub> = 6 mA		I <sub>R</sub> = 6 mA P <sub>IN</sub> = 30 W, 100 Mi I <sub>F</sub> = 50 mA		$P_{IN} = 0 \text{ dBm}, V_R = 0 V,$ 100 MHz	
	Тур.	Max.	Min.	Min. Typ.		Тур.	Min.	Тур.				
MA4P1200 - 401T												
MA4P1200NM - 401T												
MA4P1250 -1072T	0.85	1.0	2	8	8 80	80 90	60	70				
MA4P1250NM-1072T												
MA4P1450 -1091T												

<sup>\*</sup>Notes

## Power Dissipation and Thermal Resistance Ratings @ $T_A = +25$ °C

Package Condition		MA4P1200(NM)-401T		MA4P1250	(NM)-1072T	MA4P1450-1091T		
Style	Style P <sub>DISS</sub> $\theta_{JC}$		P <sub>DISS</sub>	θ <sub>JC</sub>	P <sub>DISS</sub>	θ <sub>JC</sub>		
В	No Heatsink	1.5 W	15°C/W	_	_	_		
Axial Lead	Lead Length 1/4"	5.5 W	15 C/VV	_	_	_		
F	No Heatsink	-	_	6 W	15°C/W	10 W	5°C/W	
MELF	Infinite Heatsink	-	_	18 W	15 C/VV	30 W	5 C/VV	

<sup>1.) &</sup>quot;NM" in the base part number signifies non-magnetic package.

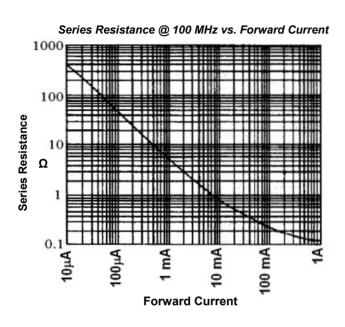
<sup>2.) &</sup>quot;T" suffix denotes tape and reel

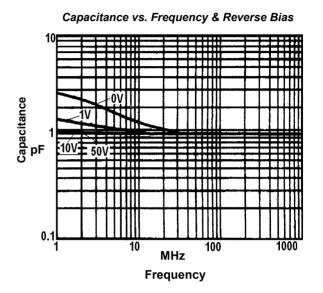


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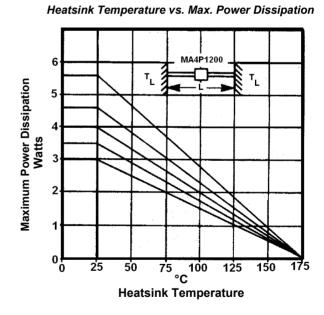
# Typical Performance Curves @ $T_A = +25$ °C MA4P1200 Series





Parallel Resistance vs. Frequency & Reverse Bias

Frequency



1000

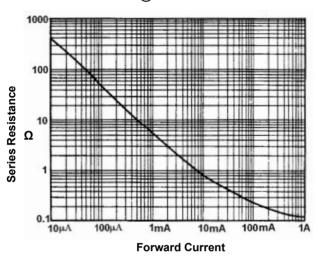


### **High Power PIN Diodes**

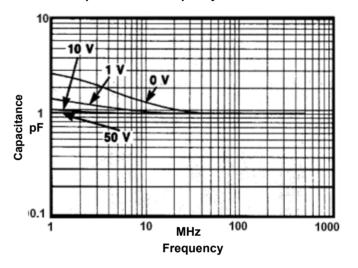
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# Typical Performance Curves @ $T_A = +25$ °C MA4P1250 Series

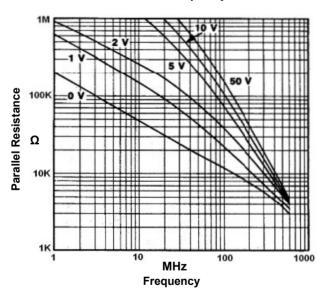
Series Resistance @ 100 MHz vs. Forward Current



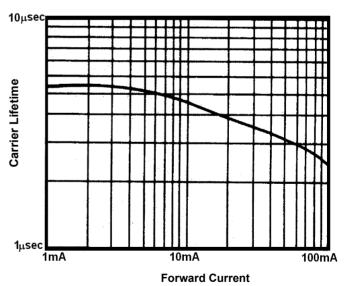
Capacitance vs. Frequency & Reverse Bias



Parallel Resistance vs. Frequency & Reverse Bias



Carrier Lifetime vs. Forward Bias Current



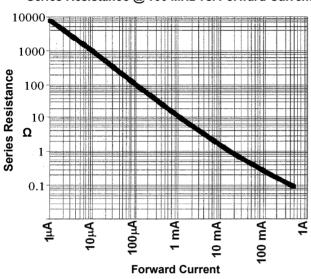


## **High Power PIN Diodes**

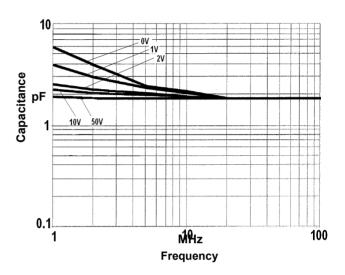
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# Typical Performance Curves @ $T_A = +25$ °C MA4P1450 Series

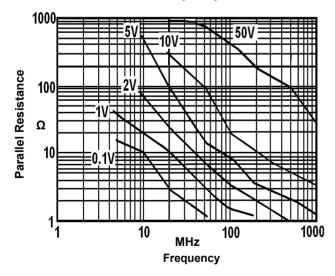
Series Resistance @ 100 MHz vs. Forward Current



#### Capacitance vs. Frequency and Reverse Bias



#### Parallel Resistance vs. Frequency and Reverse Bias





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### MA4P4000 - MA4P7100 Series Electrical Specifications @ T<sub>A</sub> = +25°C

Parameter	Symbol	Condition	MA4P4000 Series	MA4P4300 Series	MA4P7000 Series	MA4P7100 Series
Maximum Series Resistance	Rs	I <sub>F</sub> = 100 mA	0.5 Ω	1.0 Ω	0.9 Ω	0.5 Ω
Maximum Total Capacitance	C <sub>T</sub>	V <sub>R</sub> = 100 V	2.2 pF	2.0 pF	0.7 pF	1.0 pF
Minimum Parallel Resistance	R₽	V <sub>R</sub> = 100 V	20 kΩ	50 kΩ	200 kΩ	100 kΩ
Minimum Carrier Lifetime	TL	I <sub>F</sub> = 10 mA	20 μs	15 µs	5 µs	2.5 µs
Maximum Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 100 mA	1.0 V	1.2 V	1.0 V	1.0 V
Maximum Reverse Current	I <sub>R</sub>	At max. rated voltage	1 μΑ	1 μΑ	1 μΑ	1 μΑ
Nominal I-Region Width	μ	_	175 µm	300 µm	175 µm	100 µm

## Maximum Reverse Voltage Rating (V<sub>R</sub>)

Maximum Reverse Voltage Rating	MA4P4000 Series	MA4P4300 Series	MA4P7000 Series	MA4P7100 Series
100 V	MA4P4001B-402 MA4P4001BNM-402 MA4P4001F-1091T	MA4P4301B-402 MA4P4301F-1091T	MA4P7001F-1072T	MA4P7101B-401T MA4P7101F-1072T
200 V	MA4P4002B-402 MA4P4002F-1091T	MA4P4302B-402	MA4P7002B-401T MA4P7002F-1072T	MA4P7102B-401T MA4P7102F-1072T
400 V	_	_	_	MA4P7104B-401T MA4P7104F-1072T
600 V	MA4P4006F-1091T MA4P4006B-402	_	MA4P7006B-401T MA4P7006F-1072T	_

<sup>\*</sup>Notes:

<sup>2.) &</sup>quot;T" suffix denotes tape and reel.

Package Condition		MA4P4000 Series		MA4P4300 Series		MA4P7000 Series		MA4P7100 Series	
Otyle		P <sub>DISS</sub>	θ <sub>JC</sub>						
В	1/4" Lead Length	12 W	12.5°C/W	10 W	15°C/W	5 W	30°C/W	6 W	25°C/W
Axial Leaded	No Heatsink	2.5 W	_	2.5 W	_	1.5 W	_	1.5 W	_
F MELF	Infinite Heatsink	7.5 W	20°C/W	5 W	30°C/W	10 W	15°C/W	11.5 W	13°C/W
Both B and F	Single 1 µs pulse	100 kW	_	100 kW		15 kW	_	15 kW	_
Both B and F	Single 100 µs	5 kW	0.03°C/W	5 kW	0.03°C/W	300 W	0.5°C/W	300 W	0.5°C/W

<sup>1.) &</sup>quot;NM" in the base part number signifies non-magnetic package.

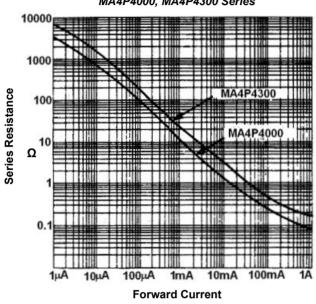


**High Power PIN Diodes** 

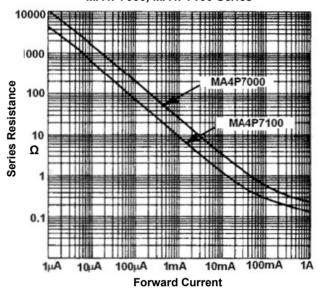
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# Typical Performance Curves @ T<sub>AMB</sub> = +25°C MA4P4000,MA4P4300, MA4P7000, MA4P7100 Series

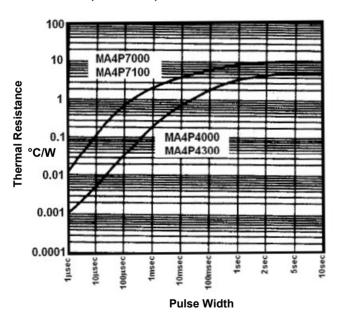
Series Resistance at 100 MHz vs. Forward Current MA4P4000. MA4P4300 Series



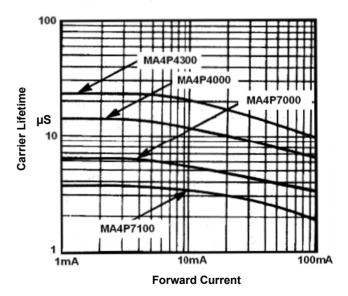
Series Resistance at 100 MHz vs. Forward Current MA4P7000, MA4P7100 Series



Thermal Resistance vs. Pulse Width MA4P4000, MA4P4300, MA4P7000 & MA4P7100 Series



Carrier Lifetime vs. Forward Bias Current MA4P4000, MA4P4300, MA4P7000 & MA4P7100 Series



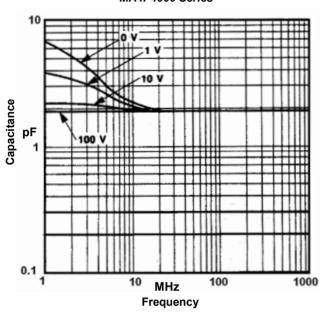


### **High Power PIN Diodes**

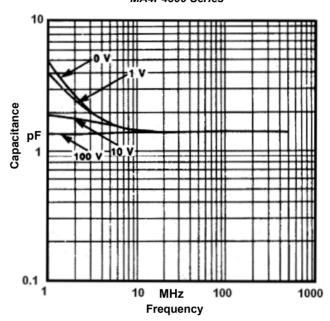
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# Typical Performance Curves @ T<sub>AMB</sub> = +25°C MA4P4000, MA4P4300, MA4P7000, MA4P7100 Series

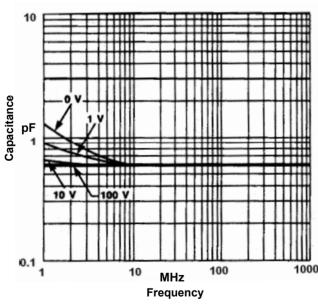
Capacitance vs. Frequency & Reverse Bias MA4P4000 Series



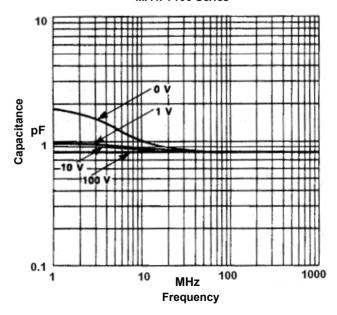
Capacitance vs. Frequency & Reverse Bias MA4P4300 Series



Capacitance vs. Frequency & Reverse Bias MA4P7000 Series



Capacitance vs. Frequency & Reverse Bias MA4P7100 Series



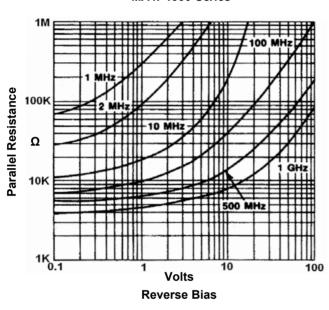


### **High Power PIN Diodes**

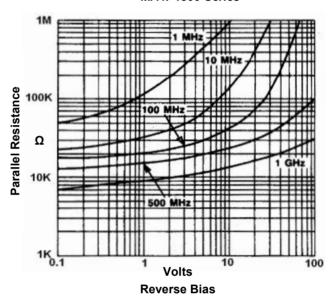
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# Typical Performance Curves @ T<sub>AMB</sub> = +25°C MA4P4000, MA4P4300, MA4P7000, MA4P7100 Series

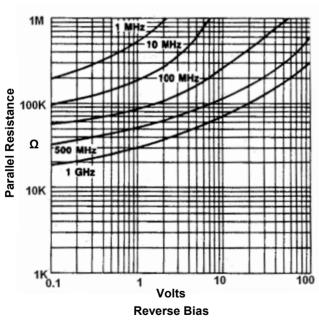
Parallel Resistance vs. Reverse Bias & Frequency
MA4P4000 Series



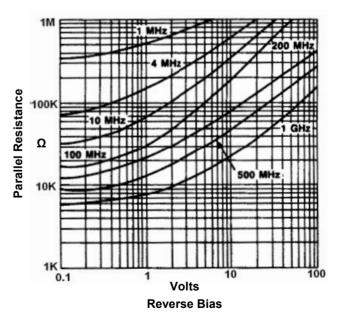
Parallel Resistance vs. Reverse Bias & Frequency
MA4P4300 Series



Parallel Resistance vs. Reverse Bias & Frequency
MA4P7000 Series



Parallel Resistance vs. Reverse Bias & Frequency MA4P7100 Series



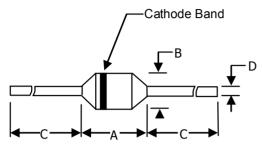


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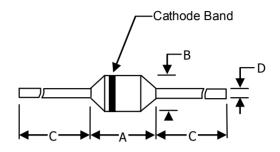
### **Case Styles**

### **401 Axial Leaded Packages**



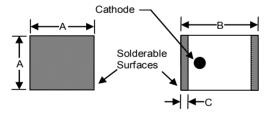
401 Package (tape and reel only)	Dimension	INC	HES	М	М
500 or 1000 pcs/reel specify when ordering	sion	Min.	Max.	Min.	Max.
MA4P1200-401T	Α	_	0.130	_	3.30
MA4P1200NM-401T MA4P7002B-401T	В	_	0.090	_	2.29
MA4P7006B-401T MA4P7101B-401T MA4P7102B-401T MA4P7104B-401T	С	0.975		24.77	_
	D	0.027	0.029	0.69	0.74

### **402 Axial Leaded Packages**



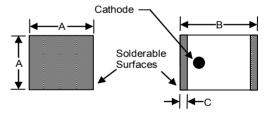
402 Package (bulk only)	Dimension	Dim INCHES		М	М
100 pcs/bag	ion	Min.	MAX	Min.	Max.
144 4D 400 4D 400	Α	_	0.230	_	5.84
MA4P4001B-402 MA4P4001BNM-402 MA4P4002B-402	В	_	0.140	_	3.56
MA4P4301B-402 MA4P4301B-402 MA4P4302B-402	С	0.975		24.77	_
	D	0.039	0.041	0.99	1.04

## 1091 MELF Surface Mount Packages



1091 Package (tape and reel only)	Dimension	INCI	INCHES		IM
500 pcs/reel	ion	Min.	Max.	Min.	Max.
MA4P1450-1091T	Α	0.138	0.155	3.51	3.94
MA4P4001F-1091T MA4P4002F-1091T MA4P4006F-1091T	В	0.181	0.191	4.57	4.85
MA4P4301F-1091T	С	0.011	0.026	0.279	0.660

### **1072 MELF Surface Mount Packages**



1072 Package (tape and reel only)	Dimension	INCHES		М	М
1500 or 5000 pcs/reel specify when ordering	ion	Min.	Max.	Min.	Max.
MA4P1250-1072T MA4P1250NM-1072T	Α	0.080	0.095	2.032	2.413
MA4P7001F-1072T MA4P7002F-1072T MA4P7006F-1072T	В	0.115	0.125	2.921	3.175
MA4P7101F-1072T MA4P7104F-1072T	O	0.008	0.023	0.203	0.584



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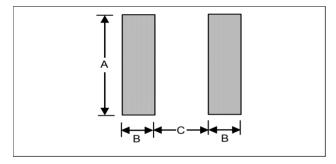
### **MELF Assembly Recommendations**

Devices may be soldered using standard 60Sn/40Pb or RoHS compliant solders. Axial leads and solderable surfaces of MELF devices are tin plated 50 µm thick to ensure an optimum connection.

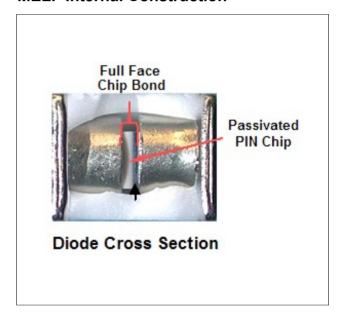
For recommended Sn/Pb and RoHS soldering profiles See Application Note M538 on the MACOM website.

### **Circuit Pad Layout for MELF Diodes**

	Package Style							
Dimension	107	′2	1091					
	inches	mm	inches	mm				
Α	0.093	2.36	0.150	3.81				
В	0.050	1.27	0.050	1.27				
С	0.060	1.52	0.100	2.54				



#### **MELF Internal Construction**



#### **Ordering Information**

MELF diodes are available in tape and reel in quantities as shown in table below

Package Style	Quantity (7" Reel)	Bulk Devices Per Bag
1072T	1500 or 5000	N/A
1091T	500	N/A

Tape and reel information can be found in application note M513 the MACOM website.



### **High Power PIN Diodes**

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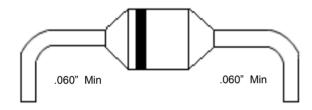
### **Axial Leaded HIPAX Assembly Recommendations**

Bends on case styles 401 and 402, axially leaded devices, must be made while holding the lead firm and forming the bend no closer than .060 inches from the body of the part. Bending the lead <0.060 inches from the body of the part is not recommended and may cause internal damage to the chip. Appropriate fixturing should be used.

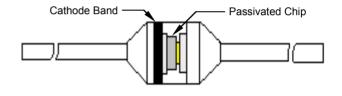
Devices may be soldered using standard 60Sn/40Pb or any RoHS compliant solders. Axial leads are tin plated  $50 \mu m$  thick to ensure an optimum connection.

For recommended Sn/Pb and RoHS soldering profiles see Application Note M538 on the MACOM website.

# Case Style 401 & 402 Minimum Bend Distance



# Case Style 401 & 402 Internal Construction



### **Ordering Information**

Axial leaded diodes are available in tape and reel or bulk in quantities shown in the table below

Package Style	Quantity Per Reel	Bulk Devices Per Bag
401T	500 or 1000 (specify qty. when ordering)	N/A
402	N/A	100

### **Environmental Ratings**

HIPAX PIN diodes are designed to meet most environmental and electrical requirements and may be ordered screened to MIL-STD-750 specifications as described in the table below.

TEST	METHOD	DESCRIPTION/ CONDITIONS
Moisture Resistance	1021	85°C, 85% Relative Humidity, 168 hrs
High Temperature Storage	1031	+175°C , 250 Hours
HTRB	1038	80% of rated V <sub>R</sub> , 50°C, 96 Hours
Temperature Shock	1051	-65°C to +175°C, 20 Cycles
Fine Leak	1071 Cond. H	1 x 10 <sup>-7</sup> CC/Sec
Constant Acceleration	2006	20,000 G's
Solderability	2026	IPC/JDEC J-STD-02
Tension <sup>1</sup>	2036.3 Cond. A	2 Lbs., 30 Seconds
Lead Fatigue <sup>1</sup>	2036.3 Cond. E	3 Cycles, 8 oz., 90°,

#### Note:

<sup>1)</sup> Test applicable to HIPAX axially leaded devices only.



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